July 2008

# FDW262P

FAIRCHILD

## 20V P-Channel PowerTrench<sup>®</sup> MOSFET

### **General Description**

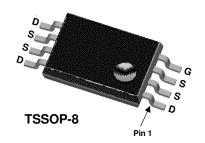
This P-Channel 1.8V specified MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

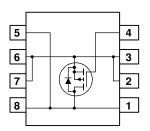
## Applications

- Power management
- Load switch

## Features

- -4.5 A, -20 V.  $R_{DS(ON)} = 47 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$   $R_{DS(ON)} = 65 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}$  $R_{DS(ON)} = 100 \text{ m}\Omega @ V_{GS} = -1.8 \text{ V}$
- $R_{DS(ON)}$  rated for use with 1.8 V logic
- Low gate charge (13nC typical)
- + High performance trench technology for extremely low  $R_{\text{DS}(\text{ON})}$
- Low profile TSSOP-8 package





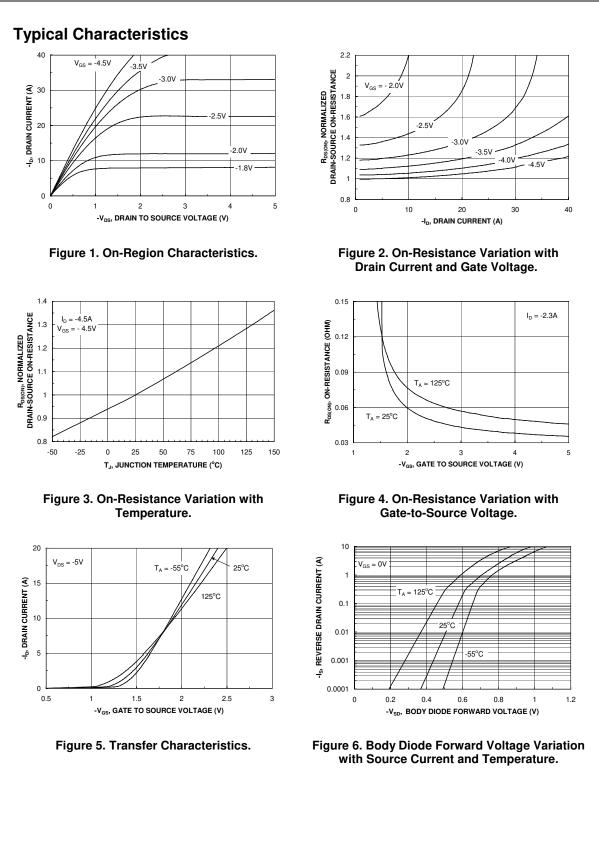
## Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage		-20	V
V <sub>GSS</sub>	Gate-Source Voltage		±8	V
I <sub>D</sub>	Drain Current – Continuous	(Note 1a)	-4.5	A
	– Pulsed		-40	
P <sub>D</sub>	Power Dissipation for Single Operation	(Note 1a)	1.3	W
		(Note 1b)	0.6	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperation	ature Range	-55 to +150	
Therma	al Characteristics			
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambien	t (Note 1a)	87	°C/W
		(Note 1b)	133	°C/W
Dackad	e Marking and Ordering Inf	ormation		
гаскау		Reel Size	Tape width	Quantity
-	Marking Device F	Reel Size	Tupe main	Guarriery

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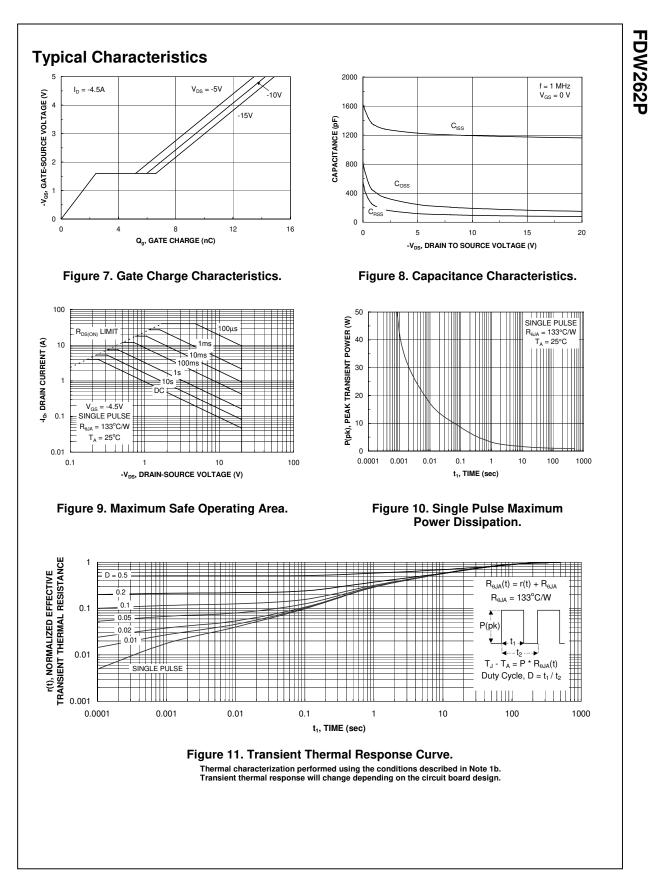
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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV <sub>DSS</sub>	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-20			V
<u>ΔBV<sub>DSS</sub></u> ΔTj	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , Referenced to 25°C		-14		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -16 V$ , $V_{GS} = 0 V$			-1	μA
I <sub>GSSF</sub>	Gate-Body Leakage, Forward	$V_{\text{GS}} = 8 \text{ V}, \qquad V_{\text{DS}} = 0 \text{ V}$			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage, Reverse	$V_{GS} = -8 V$ $V_{DS} = 0 V$			-100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-0.4	-0.8	-1.5	V
$\Delta V_{GS(th)} \Delta T_{J}$	Gate Threshold Voltage Temperature Coefficient	I <sub>D</sub> = -250 μA, Referenced to 25°C		2.5		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = -4.5 \ V,  I_D = -4.5 \ A \\ V_{GS} = -2.5 \ V,  I_D = -3.7 \ A \\ V_{GS} = -1.8 \ V,  I_D = -3 \ A \\ V_{GS} = -4.5 \ V, \ I_D = -4.5 \ A, \ T_J = 125^\circ C \end{array} $		37 50 77 48	47 65 100 65	mΩ
I <sub>D(on)</sub>	On-State Drain Current	$V_{GS} = -4.5 V$ , $V_{DS} = -5 V$	-20			Α
<b>g</b> fs	Forward Transconductance	$V_{DS} = -5 V$ , $I_{D} = -4.5 A$		16		S
Dvnamic	Characteristics					
C <sub>iss</sub>	Input Capacitance	$V_{DS} = -10 V$ , $V_{GS} = 0 V$ ,		1193		pF
Coss	Output Capacitance	f = 1.0  MHz		193		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			96		pF
Switchin	g Characteristics (Note 2)					
t <sub>d(on)</sub>	Turn–On Delay Time	$V_{DD} = -10 V$ , $I_D = -1 A$ ,		11	20	ns
t <sub>r</sub>	Turn–On Rise Time	$V_{GS} = -4.5 \text{ V}, \qquad R_{GEN} = 6 \Omega$		9	18	ns
t <sub>d(off)</sub>	Turn-Off Delay Time			36	57	ns
t <sub>f</sub>	Turn–Off Fall Time			19	34	ns
Qg	Total Gate Charge	$V_{\text{DS}} = -10 \ V, \qquad I_{\text{D}} = -4.5 \ \text{A},$		13	18	nC
Q <sub>gs</sub>	Gate–Source Charge	$V_{GS} = -4.5 V$		2.5		nC
Q <sub>gd</sub>	Gate-Drain Charge			3.6		nC
Drain-Se	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain-Source	Diode Forward Current			-1.1	А
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 \ V,  I_S = -1.1 \ A  (Note 2)$		-0.7	-1.2	V
	<ul> <li>a) 87°C/W when mounted on a of 2 oz coppe</li> </ul>	nined by the user's board design.	b) -	s the solde 133°C/W w on a minimu copper.	hen mount	ed



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FDW262P Rev C1(W)



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